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With the principle of "Quality Parts,Customers Priority,Honest Operation,and Considerate Service",our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

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## Schottky Diode Gen <sup>2</sup>

$$V_{RRM} = 100V$$

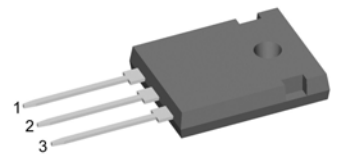
$$I_{FAV} = 2 \times 25A$$

$$V_F = 0.72V$$

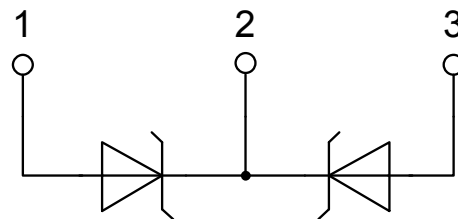
High Performance Schottky Diode  
Low Loss and Soft Recovery  
Common Cathode

Part number

DSA50C100HB



Backside: cathode



### Features / Advantages:

- Very low  $V_f$
- Extremely low switching losses
- Low  $I_{rm}$  values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

### Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

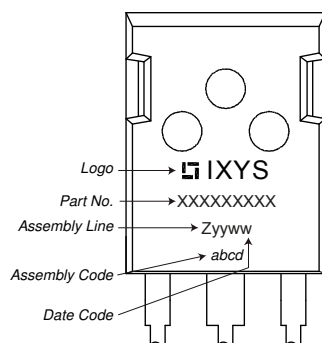
### Package: TO-247

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

| Schottky   |                                              |                                                                    |                                | Ratings                        |      |      |               |
|------------|----------------------------------------------|--------------------------------------------------------------------|--------------------------------|--------------------------------|------|------|---------------|
| Symbol     | Definition                                   | Conditions                                                         |                                | min.                           | typ. | max. | Unit          |
| $V_{RSM}$  | max. non-repetitive reverse blocking voltage | $T_{VJ} = 25^{\circ}\text{C}$                                      |                                |                                |      | 100  | V             |
| $V_{RRM}$  | max. repetitive reverse blocking voltage     | $T_{VJ} = 25^{\circ}\text{C}$                                      |                                |                                |      | 100  | V             |
| $I_R$      | reverse current, drain current               | $V_R = 100\text{ V}$                                               | $T_{VJ} = 25^{\circ}\text{C}$  |                                |      | 450  | $\mu\text{A}$ |
|            |                                              | $V_R = 100\text{ V}$                                               | $T_{VJ} = 125^{\circ}\text{C}$ |                                |      | 5    | mA            |
| $V_F$      | forward voltage drop                         | $I_F = 25\text{ A}$                                                | $T_{VJ} = 25^{\circ}\text{C}$  |                                |      | 0.90 | V             |
|            |                                              | $I_F = 50\text{ A}$                                                |                                |                                |      | 1.07 | V             |
|            |                                              | $I_F = 25\text{ A}$                                                | $T_{VJ} = 125^{\circ}\text{C}$ |                                |      | 0.72 | V             |
|            |                                              | $I_F = 50\text{ A}$                                                |                                |                                |      | 0.90 | V             |
| $I_{FAV}$  | average forward current                      | $T_C = 155^{\circ}\text{C}$<br>rectangular $d = 0.5$               | $T_{VJ} = 175^{\circ}\text{C}$ |                                |      | 25   | A             |
| $V_{F0}$   | threshold voltage                            | } for power loss calculation only                                  |                                | $T_{VJ} = 175^{\circ}\text{C}$ |      | 0.45 | V             |
| $r_F$      | slope resistance                             |                                                                    |                                |                                |      | 7.3  | m $\Omega$    |
| $R_{thJC}$ | thermal resistance junction to case          |                                                                    |                                |                                |      | 0.95 | K/W           |
| $R_{thCH}$ | thermal resistance case to heatsink          |                                                                    |                                |                                | 0.25 |      | K/W           |
| $P_{tot}$  | total power dissipation                      | $T_C = 25^{\circ}\text{C}$                                         |                                |                                |      | 160  | W             |
| $I_{FSM}$  | max. forward surge current                   | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}; V_R = 0\text{ V}$ | $T_{VJ} = 45^{\circ}\text{C}$  |                                |      | 440  | A             |
| $C_J$      | junction capacitance                         | $V_R = 12\text{ V}$ $f = 1\text{ MHz}$                             | $T_{VJ} = 25^{\circ}\text{C}$  |                                | 289  |      | pF            |

| Package TO-247 |                              |                            | Ratings |      |      |      |
|----------------|------------------------------|----------------------------|---------|------|------|------|
| Symbol         | Definition                   | Conditions                 | min.    | typ. | max. | Unit |
| $I_{RMS}$      | RMS current                  | per terminal <sup>1)</sup> |         |      | 50   | A    |
| $T_{VJ}$       | virtual junction temperature |                            | -55     |      | 175  | °C   |
| $T_{op}$       | operation temperature        |                            | -55     |      | 150  | °C   |
| $T_{stg}$      | storage temperature          |                            | -55     |      | 150  | °C   |
| Weight         |                              |                            |         | 6    |      | g    |
| $M_D$          | mounting torque              |                            | 0.8     |      | 1.2  | Nm   |
| $F_C$          | mounting force with clip     |                            | 20      |      | 120  | N    |

### Product Marking



### Part number

D = Diode  
 S = Schottky Diode  
 A = low VF  
 50 = Current Rating [A]  
 C = Common Cathode  
 100 = Reverse Voltage [V]  
 HB = TO-247AD (3)

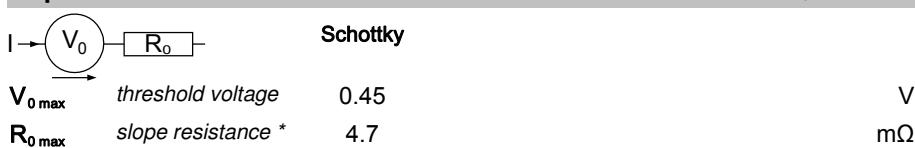
| Ordering | Part Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-------------|--------------------|---------------|----------|----------|
| Standard | DSA50C100HB | DSA50C100HB        | Tube          | 30       | 502774   |

| Similar Part | Package      | Voltage class |
|--------------|--------------|---------------|
| DSA50C100QB  | TO-3P (3)    | 100           |
| DSA60C100PB  | TO-220AB (3) | 100           |

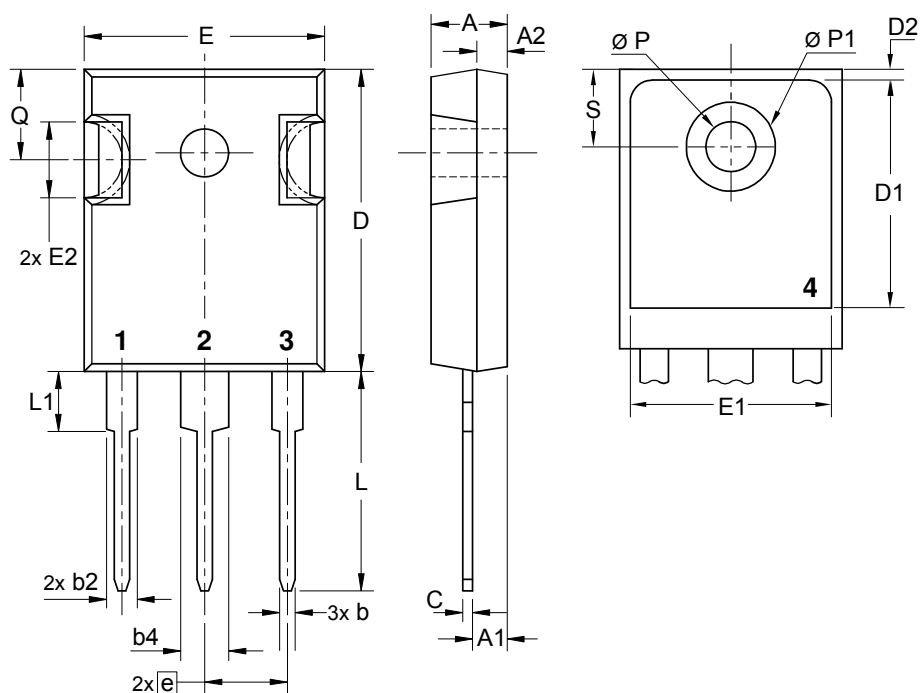
### Equivalent Circuits for Simulation

\* on die level

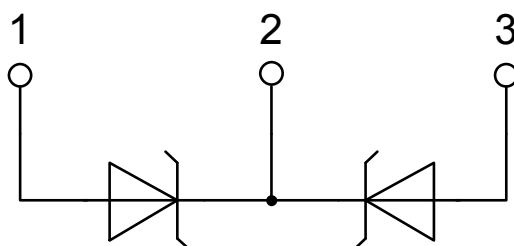
$T_{VJ} = 175^{\circ}\text{C}$



## Outlines TO-247



| Sym. | Inches |       | Millimeter |       |
|------|--------|-------|------------|-------|
|      | min.   | max.  | min.       | max.  |
| A    | 0.185  | 0.209 | 4.70       | 5.30  |
| A1   | 0.087  | 0.102 | 2.21       | 2.59  |
| A2   | 0.059  | 0.098 | 1.50       | 2.49  |
| D    | 0.819  | 0.845 | 20.79      | 21.45 |
| E    | 0.610  | 0.640 | 15.48      | 16.24 |
| E2   | 0.170  | 0.216 | 4.31       | 5.48  |
| e    | 0.215  | BSC   | 5.46       | BSC   |
| L    | 0.780  | 0.800 | 19.80      | 20.30 |
| L1   | -      | 0.177 | -          | 4.49  |
| Ø P  | 0.140  | 0.144 | 3.55       | 3.65  |
| Q    | 0.212  | 0.244 | 5.38       | 6.19  |
| S    | 0.242  | BSC   | 6.14       | BSC   |
| b    | 0.039  | 0.055 | 0.99       | 1.40  |
| b2   | 0.065  | 0.094 | 1.65       | 2.39  |
| b4   | 0.102  | 0.135 | 2.59       | 3.43  |
| c    | 0.015  | 0.035 | 0.38       | 0.89  |
| D1   | 0.515  | -     | 13.07      | -     |
| D2   | 0.020  | 0.053 | 0.51       | 1.35  |
| E1   | 0.530  | -     | 13.45      | -     |
| Ø P1 | -      | 0.29  | -          | 7.39  |



## Schottky

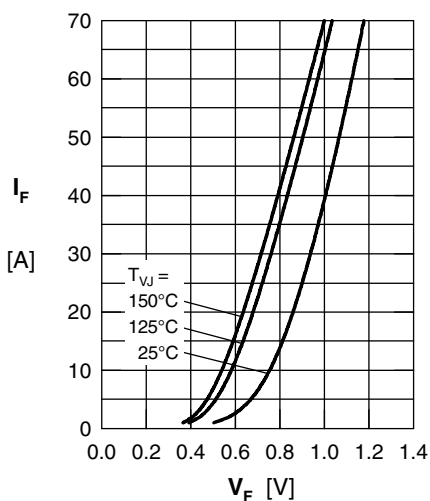


Fig. 1 Maximum forward voltage drop characteristics

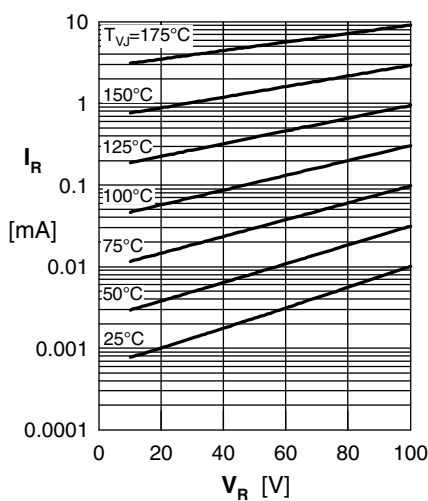


Fig. 2 Typ. reverse current  $I_R$  vs. reverse voltage  $V_R$

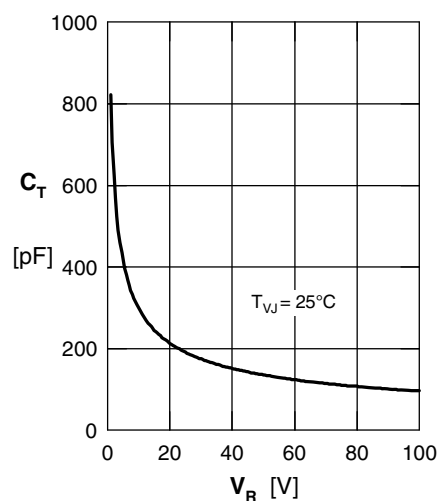


Fig. 3 Typ. junction capacitance  $C_T$  vs. reverse voltage  $V_R$

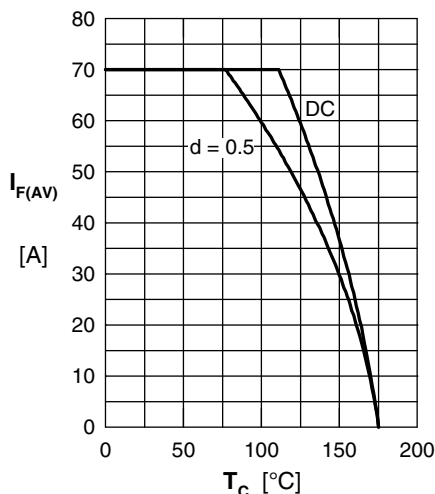


Fig. 4 Average forward current  $I_{F(AV)}$  vs. case temperature  $T_C$

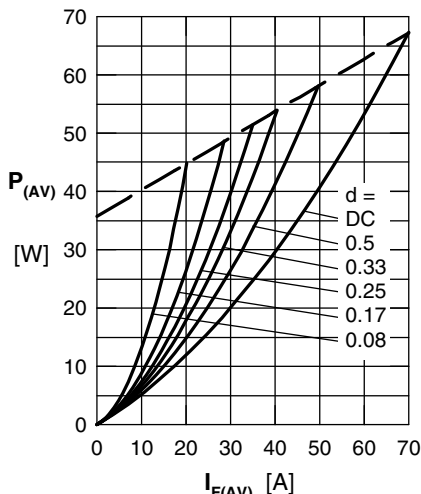


Fig. 5 Forward power loss characteristics

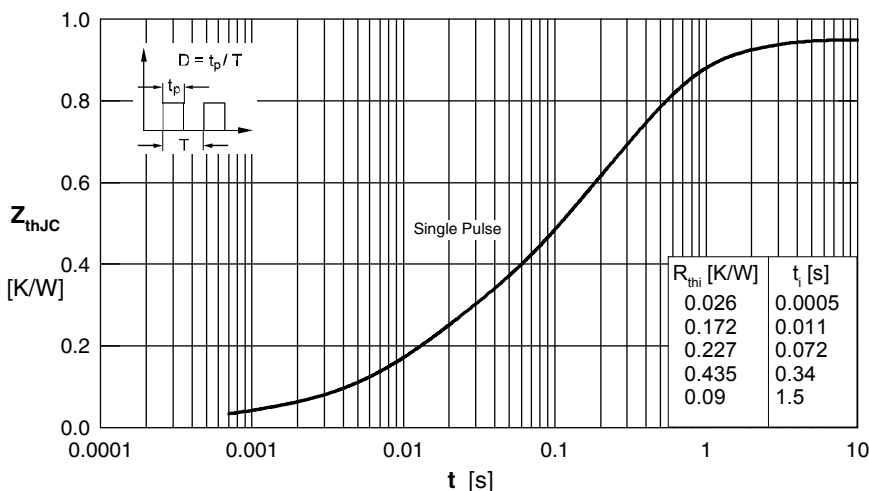


Fig. 6 Transient thermal impedance junction to case

Note: All curves are per diode